

Electromagnetism

Electrostatic Fields

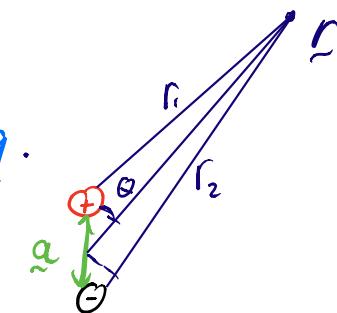
- Coulomb showed that $E = \frac{1}{4\pi\epsilon_0} \frac{q_1 q_2}{r^2} \hat{r}$
- The potential difference between two points is the work per unit charge to move a small test charge from A to B. $V_{BA} = - \int_A^B E(r) \cdot dr$
- ↳ alternatively, $E(r) = -\nabla V(r)$
- ↳ V only defined to within a constant offset - this constant is the gauge of the field.
- ↳ by summing the p.d.s across a small loop, we can derive $\nabla \times E = 0$. essentially a consequence of Stokes' theorem
- ↳ potentials add by linear superposition
- We can analyse how potentials vary in space using Poisson's equation $\nabla^2 V(r) = -\frac{\rho(r)}{\epsilon_0}$
- ↳ we can solve for V if we know $\rho(r)$ and the B.C.s
- ↳ when there is no charge, Poisson \rightarrow Laplace's equation.
- ↳ we can either specify the quantity (Dirichlet), normal derivative of the quantity (Neumann) or both (Cauchy) as boundary conditions

- B.C.s guarantee uniqueness to within an additive const.
- ↳ can be shown by assuming there exist two solutions and examining $\Phi(r) = V(r) - U(r)$
- ↳ then use identity $\nabla \cdot (\Phi \nabla \Phi) = |\nabla \Phi|^2 + \Phi \nabla^2 \Phi$ and integrate both sides over the total volume
- ↳ $\Phi=0$ on boundary and $\nabla \Phi=0$ everywhere $\Rightarrow U=V$

- Poisson's equation can be solved with the Green's function, the solution of $\nabla^2 G(r, r') = -\delta(r-r')$ which satisfies homogeneous B.C.s, i.e. $aG + bG' = 0$ at each point on the boundary
- ↳ once G is known, we can find the potential via $V(r) = \frac{1}{\epsilon_0} \int_V G(r, r') \rho(r') dV'$

Dipoles

- A monopole is a single point charge q .
 - At large distances away:
- $$r_1 \approx r - a/2 \cos\theta$$
- $$r_2 \approx r + a/2 \cos\theta$$
- Then, the dipole potential is $V(r) = \frac{q}{4\pi\epsilon_0} \left(\frac{1}{r_1} - \frac{1}{r_2} \right)$
 - ↳ expand in a/r and let $p = qa$ be the electric dipole moment to get $V = \frac{p \cos\theta}{4\pi\epsilon_0 r^2}$



$$V = \frac{p \cos\theta}{4\pi\epsilon_0 r^2}$$

- The gradient in spherical coordinates is:

$$\nabla V = \frac{\partial V}{\partial r} \hat{r} + \frac{1}{r} \frac{\partial V}{\partial \theta} \hat{\theta} + \frac{1}{r \sin \theta} \frac{\partial V}{\partial \phi} \hat{\phi}$$

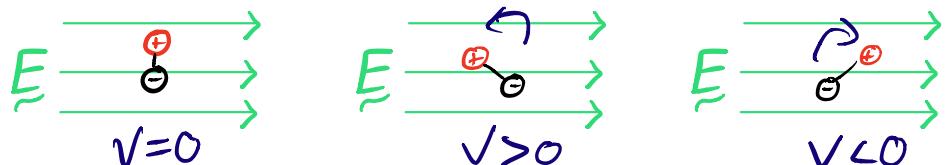
- Hence the electric field of a dipole is:

$$\underline{E}(r, \theta) = \frac{p}{4\pi\epsilon_0 r^3} (2\cos\theta \hat{r} + \sin\theta \hat{\theta})$$

- If a dipole is placed in a uniform field, it experiences a couple: $\underline{G} = \underline{p} \times \underline{E}$ ($G = \underline{p} \times \underline{E} = q \underline{d} \times \underline{E}_0$)

$|G| = p E \sin\theta \Rightarrow$ couple is zero when dipole aligned to \underline{E}

\hookrightarrow a dipole thus has potential energy since work is done to rotate it in a field ($dW = |G(\theta)|/d\theta$)



\hookrightarrow with this (arbitrary) convention:

- When the field is non-uniform, we can Taylor-expand the field:

$$E_x^+ \approx E_x^- + \underline{q} \cdot \nabla E_x$$

and $F_x = q(E_x^+ - E_x^-)$

\hookrightarrow repeating this for y and z , we can show that: $\underline{F} = (\underline{q} \cdot \nabla) \underline{E}$ \leftarrow NB: grad of a vector field

\hookrightarrow if \underline{p} is constant, we can say:

$$\underline{E}(r) = \nabla(p \cdot \underline{E}(r)) = -\nabla V(r) \quad \leftarrow \text{rotational PE}$$

\hookrightarrow in reality, the dipole will move and \underline{E} must be recalculated

- Consider a dipole within a uniform field. The potential at some point is:

$$V(r) = -E_0 r \cos\theta + \frac{p \cos\theta}{4\pi\epsilon_0 r^2}$$

\hookrightarrow there is thus a spherical surface for which $V=0$.

\hookrightarrow we could replace this with a spherical conductor and still satisfy the B.C.s - by uniqueness, this must be the solution.

- Thus a uniform conductor in a field is equivalent to a dipole \Rightarrow induced dipole, with moment:

$$p = \underbrace{4\pi\epsilon_0 a^3}_{\alpha} E_0$$

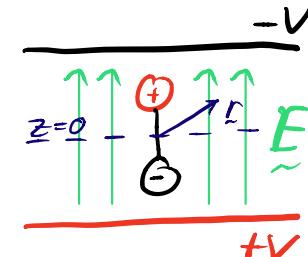
α is the polarisability

\hookrightarrow then we have $\underline{p} = \alpha \underline{E}_0$

\hookrightarrow the induced charge is not 'because of' the dipole

\hookrightarrow in general, α will be a tensor because \underline{p} and \underline{E}_0 need not align.

We can now calculate $V(r)$ and $\underline{E}(r)$. The surface charge density of the sphere is given by: $\sigma_r = \frac{\alpha}{\epsilon_0}$

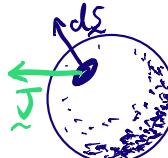


- In principle, we can analyse more complex charge distributions using **multipole expansions**.
 - ↳ e.g. a quadrupole field drops off as $1/r^3$
 - ↳ multipole potentials form a complete set of functions

The divergence of E Fields

- **Electric flux** is a mathematical concept related to the density of field lines through a patch: $\oint_S \mathbf{E} \cdot d\mathbf{S}$
- From the divergence theorem: $\oint_S \mathbf{E} \cdot d\mathbf{S} = \int_V \nabla \cdot \mathbf{E} dV$

- Div. theorem can be combined with charge conservation
 - ↳ consider some volume with a current density \mathbf{J} at some point on the surface



↳ by cons. charge:

$$I = \oint_S \mathbf{J} \cdot d\mathbf{S} = -\frac{\partial}{\partial t} \int_V \rho dV = \int_V \nabla \cdot \mathbf{J} dV$$

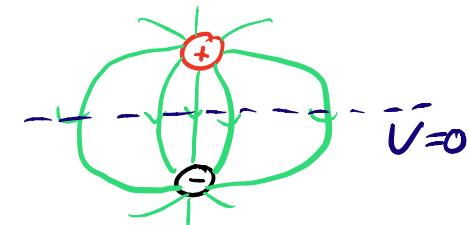
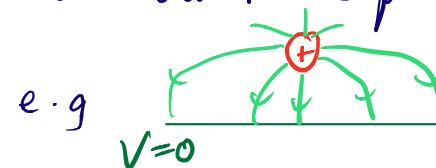
div. theorem

$$\Rightarrow \frac{\partial \rho}{\partial t} + \nabla \cdot \mathbf{J} = 0$$

- It can also be used to derive **Gauss' law** by considering the flux from a point charge. Define the **electric displacement** of free space $D(r) = \epsilon_0 E(r)$
- ∴ $\oint_S D(r) \cdot d\mathbf{S} = Q_{enc} \Leftrightarrow D \cdot \nabla D(r) = \rho(r)$ actually this is only free charge

The method of images

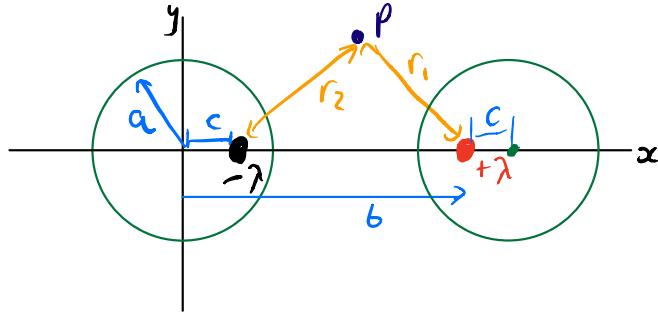
- Generalises the approach used to analyse spherical conductor in E field.
- By uniqueness, if we can construct some charge dist. that fits the B.C.s, that solution is the solution.
- The method of images can be used to calculate potentials and fields in the presence of a conductor.



↳ we can introduce image charges such that the potential is equivalent to if there were a conductor.

↳ these images must not be in the same region where you want to calculate potential.

- The surface charge density on the conductor can be calculated using the B.C. $\sigma = \epsilon_0 E_\perp$
- The energy of an image arrangement can be found using $W = \frac{1}{2} \iiint \rho V d\tau = \frac{1}{2} \sum q_i V_i$
 - ↳ be careful when integrating because image charges move too.
- The image for a line charge parallel to a cylindrical conductor is a line charge inside the cylinder.

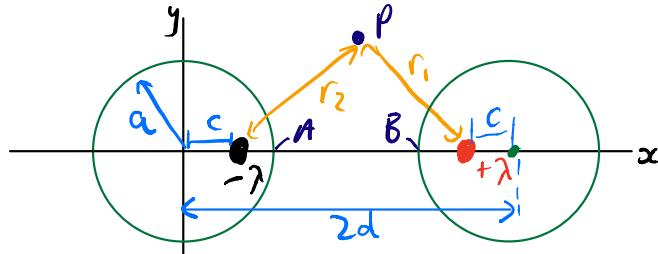


- $V(C) = \frac{1}{2\pi\epsilon_0} \ln\left(\frac{r_2}{r_1}\right) \Rightarrow \frac{r_2^2}{r_1^2} = k = \text{const}$ for equipotentials.
↳ expanding out shows that $c = a^2/b$

Capacitance

- The capacitance of a two-surface metallic structure is the amount of net positive charge on the high-potential surface divided by the p.d. $C = Q/V$

- Consider the system of two parallel cylindrical conductors, with separation $2d$.



$$\hookrightarrow c = a^2/b = a^2/2d - c \quad \therefore c = d - \sqrt{d^2 - a^2}$$

↳ we can choose easy points A, B to evaluate V

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$$\hookrightarrow \text{the potential is then } V = \frac{1}{\pi\epsilon_0} \ln\left(\frac{a}{d - \sqrt{d^2 - a^2}}\right)$$

$$\hookrightarrow \text{in the } d \gg a \text{ limit: } C \approx \frac{\pi\epsilon_0}{\ln(2d/a)}$$

Electrostatic energy

- By building up a set of charges, it can be shown that:

$$U = \frac{1}{2} \sum_{i=1}^N q_i V_i \quad \leftarrow V_i \text{ is the potential at position } i \text{ without } i\text{th charge}$$

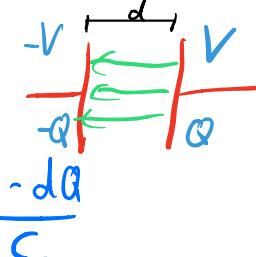
- In the continuous case:

$$U = \frac{1}{2} \iiint \rho(r) V(r) dr \quad \leftarrow V(r) \text{ must exclude the charge element at } r.$$

- Consider a parallel-plate capacitor

$$\hookrightarrow \text{let } Q = \int dQ \text{ and by excluding}$$

$$\text{the charge element we have } V = \frac{Q - dQ}{C}$$



- ↳ the energy in the capacitor is:

$$U = \frac{1}{2} \int V dQ = \frac{1}{2} \int \frac{Q - dQ}{C} dQ \rightarrow O(dQ)^2 \rightarrow 0$$

$$\therefore U = \frac{1}{2} QV = \frac{1}{2} CV^2$$

- We can also derive this by considering the field:

$$U = \frac{1}{2} QV = \frac{1}{2} (A\epsilon_0 |E|) (|E|/d)$$

$$\therefore U_E(r) = \frac{1}{2} \epsilon_0 |E(r)|^2 = \frac{1}{2} D(r) \cdot E(r)$$

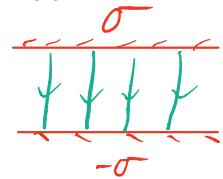
↑ energy density

↳ then $U = \iiint U_C(r) d\tau$

↳ we could also have found this using

$$U = \frac{1}{2} \iiint \rho(r) V(r) d\tau = \frac{1}{2} \epsilon_0 \iiint (\nabla \cdot E) V(r) d\tau$$

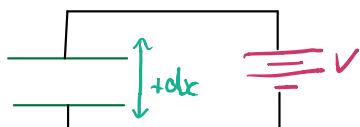
then applying an identity.



Forces on charge distributions

- The method of virtual work calculates the force by considering how a small perturbation dx changes the energy of the system.

- Consider a capacitor held at constant potential, with a perturbation dx increasing the separation



↳ the electric field (and thus energy) decreases with separation.

$$U_s = \frac{1}{2} \epsilon_0 \frac{V^2}{x} A \quad \therefore dW = \frac{\partial U_s}{\partial x} dx = -\frac{1}{2} \epsilon_0 \frac{V^2}{x^2} A dx$$

↳ but the decrease in charge on the plates causes power dissipation in the battery

$$dW = -V dQ, \quad Q = \frac{V}{2} \epsilon_0 A \quad \therefore dW = \epsilon_0 \frac{V^2}{x^2} A dx$$

↳ considering both of these energy changes:

$$Fd\tau = -\frac{1}{2} \epsilon_0 \frac{V^2}{x^2} A dx + \epsilon_0 \frac{V^2}{x^2} A dx$$

$$\therefore F = \frac{1}{2} \epsilon_0 V^2 \frac{A}{x^2}$$

- The electric field between two charged conductors is $|E| = \frac{\sigma}{\epsilon_0}$

- However, to find the force (without virtual work), we must exclude the current plate.

$$\therefore F = Q |E| = \sigma A \cdot \frac{\sigma}{2\epsilon_0} = \frac{Q^2}{2\epsilon_0 A}$$

↳ this is an attractive force obviously

Dielectrics

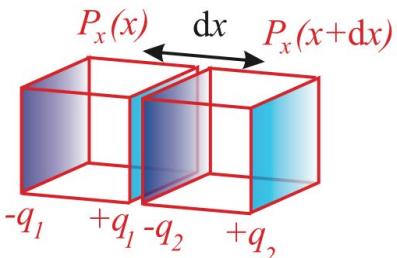
- When an insulator is placed in an electric field, dipole moments are induced. These are **bound charges**, as opposed to the **free charges** in conductors.
 - ↳ this charge only appears on surfaces because internally the bound charges cancel.
 - ↳ this is quantified by the **polarisation**, which is the dipole moment per unit volume

$$\text{number density of atoms} \cdot P = N_p \Rightarrow |P| = \frac{Q}{A}$$
- With a dielectric in a capacitor at fixed potential, the free charge on the plates must increase to compensate for the bound charge at the surface.
 - ↳ the charge increases by a factor of ϵ_r , which is the **relative permittivity** of the dielectric.
 - ↳ $\therefore C = \frac{Q}{V} = \frac{\epsilon_r \epsilon_0 A}{d}$. Q is only the free charge!
- If the electric field is non-uniform, there will be some polarisation charge density within the dielectric

$$q = q_1 - q_2 = [P_x(x) \cdot P_x(x+dx)] dy dz = -\frac{\partial P_x}{\partial x} dx dy dz$$

$$\therefore P_b = -\nabla \cdot P(r)$$

↳ P_b is the bound/polarisation charge.



- In general, some volume of space may contain both free and bound charges. Applying Gauss' law:

$$\int_S \underline{E} \cdot d\underline{S} = \frac{1}{\epsilon_0} \int_V P_{\text{total}} dV = \frac{1}{\epsilon_0} \int_V P_f + P_b dV$$

$$\Rightarrow \int_V \nabla \cdot \underline{E} dV = \frac{1}{\epsilon_0} \int_V P_f - \nabla \cdot \underline{P} dV$$

$$\Rightarrow \nabla \cdot [\epsilon_0 \underline{E} + \underline{P}] = P_f$$

↳ we define the **electric displacement field** $\underline{D} = \epsilon_0 \underline{E} + \underline{P}$

$$\therefore \nabla \cdot \underline{D} = P_f \quad \text{↳ free charge is the source of } \underline{D}$$

↳ in a linear dielectric (e.g. if \underline{E} is small), polarisation is proportional to the field where the constant is the **susceptibility**, $\chi = \epsilon_r - 1$. Using $\epsilon_r = 1 + \chi$:

$$D(x) = \epsilon_r \epsilon_0 E(x)$$

- The original Maxwell equation $\nabla \cdot \underline{E} = \frac{\rho}{\epsilon_0}$ is still valid, but formulating in terms of \underline{D} is easier because it absorbs the effects of the dielectric into a constant.

- For electrostatics problems with fixed potentials, the electric field will be the same because of the uniqueness theorem

① E from V ② D from E ③ σ from D

Poisson's eq, $E = \nabla V$

$$D = \epsilon_r \epsilon_0 E$$

Gauss' law

- If charge is fixed (i.e. P_f known) on all surfaces

① D from P_f ② E from D ③ V from E

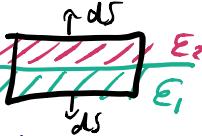
Gauss' law

$$E = D / \epsilon_r \epsilon_0$$

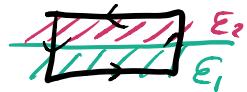
$$V = - \int \underline{E} \cdot d\underline{l}$$

Boundary conditions

- To understand the B.C.s, we can construct a Gaussian pillbox. Since $P_F = 0$, we must have $D_{2\perp} = D_{1\perp}$. $D = \epsilon_r \epsilon_0 E$, so E_\perp is discontinuous.

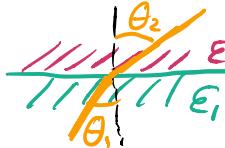


- Constructing a loop and using $\oint \mathbf{E} \cdot d\mathbf{l} = 0$, we must have $E_{1\parallel} = E_{2\parallel} \therefore D_\parallel$ discontinuous.



- Hence, though D and E are everywhere parallel to each other, the direction of the field lines changes at a boundary:

$$\frac{\tan \theta_1}{\tan \theta_2} = \frac{E_1}{E_2}$$



- For simple geometries, B.C.s can be applied directly to find P (normally the quantity of interest).

- Long thin rod parallel to uniform field:

$$\hookrightarrow E_{\parallel, \text{cont.}} \therefore E_{in} = E_0 \therefore P = \epsilon_0 \chi E$$



- Thin slab perpendicular to uniform field:

$$\hookrightarrow D_{\perp, \text{cont.}} \therefore E_{in} = \frac{1}{\epsilon_r} E_0$$

$$\Rightarrow P = \epsilon_0 E_0 \frac{\chi}{1+\chi} \leftarrow \begin{matrix} \text{this form of relationship} \\ \text{is very common} \end{matrix}$$



- Dielectric sphere in uniform field:

\hookrightarrow guess that internal field is uniform and externally there is some dipole field due to surface polarisation charge:



$$V_{in} = -E_{in} r \cos \theta$$

$$V_{out} = -E_0 r \cos \theta + \frac{A \cos \theta}{r^2}$$

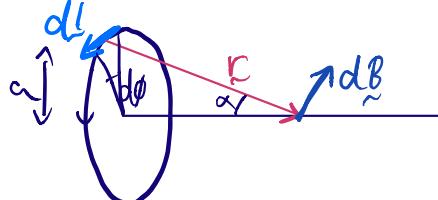
- $V_{in} = V_{out}$ at boundary (equivalent to $E_{\parallel, \text{cont.}}$)
- $D_{\perp, \text{cont.}} \therefore -\epsilon_0 \epsilon_r \frac{\partial V_{in}}{\partial r}|_{r=a} = -\epsilon_0 \frac{\partial V_{out}}{\partial r}|_{r=a}$
- applying these B.C.s gives $E_{in} = \frac{3}{\epsilon_r + 2} E_0$
 $\Rightarrow P = \frac{\chi}{1 + \chi} \epsilon_0 E_0$
- by uniqueness, this is the solution.

Magnetostatics

- A current element is an infinitesimal wire filament $d\vec{l}$ carrying current I .
- The magnetic field \vec{B} is defined as $d\vec{F} = I d\vec{l} \times \vec{B}$
- The B -field produced by a current element is given by the Biot-Savart law:
$$\vec{dB} = \frac{\mu_0 I}{4\pi r^2} d\vec{l} \times \hat{r}$$
- ↳ μ_0 is the permeability of free space
- ↳ B -field is inverse square and field lines circulate
- The force between two current elements can thus be evaluated:
$$d\vec{F} = \frac{I_1 I_2 \mu_0}{4\pi r^2} d\vec{l}_1 \times (d\vec{l}_2 \times \hat{r})$$

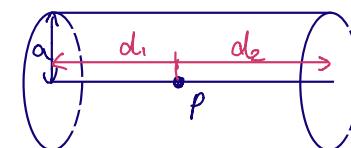
↳ greatest when elements are aligned
 ↳ attractive when currents flow in the same direction
 ↳ can be used to define the ampere.

e.g. the on-axis field of a current loop



$$\begin{aligned} B_x &= \frac{\mu_0 I}{4\pi r^2} \sin \alpha \, d\vec{l} \\ &= \frac{\mu_0 I \alpha^2}{2 r^3} \end{aligned}$$

e.g. the on-axis field of a solenoid with n loops /unit length



$$dB = \frac{\mu_0 I \alpha^2}{2 r^3} \cdot n dx$$

$$\Rightarrow B = \frac{\mu_0 n I}{2} \left[\frac{x}{\sqrt{a_1^2 + x^2}} \right] dx$$

↳ thus for a long solenoid, $a_1, a_2 \rightarrow \infty$ and hence $B = \mu_0 n I$

- Magnetic field lines form closed loops and wrap around electrical currents. Magnetic monopoles do not exist.
 ↳ thus the net magnetic flux (Φ) through a closed surface is zero.

$$\oint_S \vec{B} \cdot d\vec{l} = 0 \iff \nabla \cdot \vec{B} = 0$$

Magnetic dipoles

- A magnetic dipole is modeled as a small current loop with vector area $d\vec{S}$
 ↳ the dipole moment is $d\vec{m} = I d\vec{S}$
 ↳ the torque on this loop in a field is $d\vec{\tau} = d\vec{m} \times \vec{B}$
- For an arbitrarily-shaped loop in a field, the net torque is $\vec{\tau} = \vec{m} \times \vec{B}$, with $\vec{m} = I \int_S d\vec{l}$
 ↳ S is any surface bounded by the loop.



- The potential energy of a magnetic dipole is given by $V = -\underline{m} \cdot \underline{B}$ ← identical to electric dipole
↳ a macroscopic current loop can be constructed from many magnetic dipoles:

$$V = -\int \underline{B} \cdot d\underline{m} = -\int_I I d\underline{l} \cdot \underline{B} = -I \phi$$

- In a non-uniform field, the force on a dipole (assuming dipole moments are constant in space) is given by $\underline{F}(s) = \nabla(\underline{m} \cdot \underline{B}(s))$

Magnetic scalar potential

- Analogous to the electric potential, it is useful to define $H(s) = -\nabla \phi_m(s)$

↳ H is the magnetic field strength, from which we can get the flux density $B = \mu H$

- We can calculate ϕ_m for a loop with the concept of solid angle

- The solid angle subtended by some surface element is given by:

$$d\Omega = \frac{|d\underline{l}|}{r^2} \cos\theta$$



N.B.: inwards surface normal and \underline{l} points towards origin

- The magnetic/electric dipole fields have the same form, so for a magnetic dipole: $\phi_m(r, \theta) = \frac{|dm| \cos\theta}{4\pi r^2}$

- Using $|dm| = I |dl|$, and breaking down an arbitrary loop into infinitesimal ones: Ω is the solid angle subtended $\rightarrow \phi_m = \frac{I\Omega}{4\pi}$

- If we consider traversing some arbitrary closed path through a loop, we notice a discontinuity in ϕ_m at the centre of the loop.

$$\rightarrow \Omega = 2\pi \text{ at } A, \quad \Omega = -2\pi \text{ at } A'$$

$$\therefore \int_A^{A'} d\phi_m = -I$$

$$\rightarrow \text{but } \int_A^{A'} d\phi_m = \int_A^{A'} \nabla \phi_m \cdot d\underline{l}, \text{ which in the limit becomes } -\frac{\mu_0}{4\pi} \oint B \cdot d\underline{l}$$

↳ thus we have derived Ampere's law:

$$\oint B \cdot d\underline{l} = \mu_0 I$$

- We can find I as $I = \int \underline{J} \cdot d\underline{l}$. Using Stokes' theorem:

$$\oint \nabla \times \underline{H} = \underline{J}$$

↳ by Ohm's law: $\underline{J} = \sigma \underline{E}$

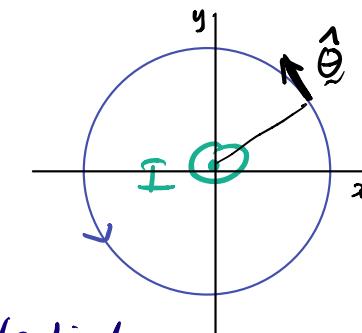
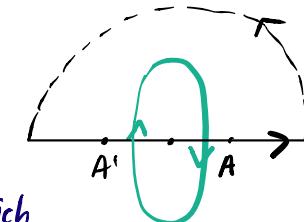
- For a long wire, the B field is:

$$B = \frac{\mu_0 I}{2\pi r} \hat{\theta}$$

- In cylindrical polar, $(\nabla) \phi = \frac{1}{r} \frac{\partial}{\partial \theta}$

∴ For a wire, $\phi_m = -\frac{I\theta}{2\pi}$

↳ i.e. increasing θ decreases potential



- However, because $\nabla \times \underline{B} \neq 0$, the magnetic potential must be multivalued, e.g. at $\theta = 0, 2\pi, 4\pi, \dots$

Magnetic vector potential

- We know that $\nabla \cdot \underline{B} = 0$, so it is reasonable to assume that we can write $\underline{B}(\underline{r}) = \nabla \times \underline{A}(\underline{r})$
- However, it can be seen that \underline{A} is undefined to within a radial vector field $\underline{k}(\underline{r})$, where $\underline{k}(\underline{r}) = (k_x(x), k_y(y), k_z(z))$ \leftarrow e.g. $\frac{\partial k_x}{\partial y} = 0$
 - ↳ $\nabla \cdot \underline{A}$ can be arbitrarily set without affecting the curl - this is known as choosing the gauge.
 - ↳ a common choice is $\nabla \cdot \underline{A}(\underline{r}) = 0$ everywhere
- Then $\nabla \times \underline{B} = \mu_0 \underline{J} \Rightarrow \boxed{\nabla^2 \underline{A} = -\mu_0 \underline{J}}$

- ↳ this is analogous to Poisson's equation, and we can conclude that $\underline{A}(\underline{r}) = \frac{\mu_0}{4\pi} \int \frac{\underline{J}(\underline{r}')}{|\underline{r} - \underline{r}'|} d^3 r'$
- ↳ we thus have a general way to compute the \underline{B} field, though in practice Biot-Savart or Ampère's laws are more useful.

Magnetic fields in matter

- The magnetic dipole of an atom fundamentally arises from the orbital motion of electrons and their spin.
- However, we model magnetisation in terms of current loops.
- **Magnetisation** (\underline{M}) is the magnetic dipole moment per unit volume - analogous to \underline{P} in electrostatics
 - ↳ the total magnetic dipole moment of an object can be found by integration: $\underline{m}_t = \int_v \underline{M} d\underline{v}$
 - ↳ \underline{M} can be associated with the fictitious magnetisation current: $\underline{J}_m = \nabla \times \underline{M}$ \leftarrow analogous to $\underline{P}_b = -\nabla \cdot \underline{P}$
 - ↳ If an object has uniform magnetisation, \underline{J}_m must reside on the surface (inner loops cancel out). The surface current density $\underline{J}_s = \underline{M} \times \hat{\underline{n}}$
 - ↳ analogous to $\sigma_p = \underline{P} \cdot \hat{\underline{n}}$

- In a magnetic material, we can consider that the resulting flux density is a result of a 'free space' field strength and the magnetisation: $\underline{B} = \mu_0(\underline{H} + \underline{M})$

↳ \underline{H} is the magnetic field strength, such that

$$\nabla \times \underline{H} = \underline{J}_{\text{free}} \quad \text{and} \quad \oint \underline{H}(\underline{r}) \cdot d\underline{l} = I$$

- ↳ these relations do not depend on the material, though to calculate forces we ultimately need \underline{B} .

- For many materials (and small field strengths), \underline{M} scales linearly with \underline{H} , i.e. $\underline{M} = \chi_m \underline{H}$ where χ_m is the magnetic susceptibility of the material.

$$\therefore \underline{B} = \mu_0(1 + \chi_m) \underline{H} = \mu_0 \mu_r \underline{H}$$

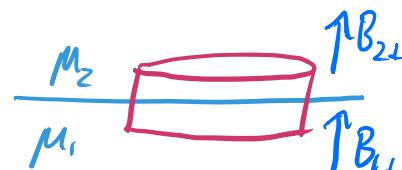
- ↳ diamagnetic $\chi_m < 0$ (small negative)
- ↳ paramagnetic $\chi_m > 0$ (small positive)
- ↳ ferromagnetic $\chi_m \gg 0$

- Some materials are permanently magnetised, with a constant magnetic dipole independent of \underline{H} .

Inhomogeneous magnetic materials

- Consider a pill box on a boundary between two magnetic materials.

$$\oint \underline{B} \cdot d\underline{s} = 0 \Rightarrow B_{1\perp} = B_{2\perp}$$



↳ normal component of \underline{B} is continuous across the boundary (and thus H_\perp is discontinuous)

↳ by setting up a loop, we can show that

$$\oint \underline{H} \cdot d\underline{l} = 0 \Rightarrow H_{1\parallel} = H_{2\parallel}$$

- This is very similar to the electrostatics case, with $\underline{B} \sim \underline{D}$, and $\underline{H} \sim \underline{E}$

↳ H, E are field strengths. B, D are flux densities.

- The B.C.s can be used to find the fields in magnetisable objects: e.g. a sphere in a uniform field



Let $\underline{H} = -\nabla \phi_m$. Assume uniform field

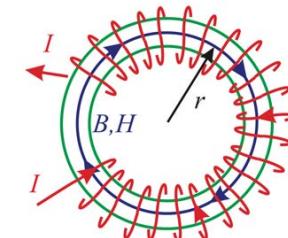
$$\therefore \phi_m(r) = \begin{cases} -H_{in} \cos \theta & r < a \\ -H_0 \cos \theta + \frac{A \cos \theta}{r^2}, & r > a \end{cases}$$

H_{\parallel} cont and $B_r = \mu_0 \mu_r \frac{\partial \phi_m}{\partial r}$ cont

$$\Rightarrow H_{in} = \frac{3}{\mu+2} H_0$$

Electromagnets

- Consider a toroidal solenoid (high permeability) with N turns of wire.
- ↳ we can analyse the system with an Amperian loop:



$$\oint \underline{H} \cdot d\underline{l} = \int_S I \cdot d\underline{z} \Rightarrow 2\pi r H_{in} = NI \Rightarrow B_{in} = \frac{\mu_r \mu_0 NI}{2\pi r}$$

- If we introduce an air gap of width L , we can model it as being a different material (\perp to B field)

↳ from B.C., $\mu_0 H_{gap} = \mu_r \mu_0 H_{in}$

↳ then from Ampere's law:

$$\oint \underline{H} \cdot d\underline{l} = (2\pi r - L) H_{in} + L H_{gap} = NI$$

$$\Rightarrow B_{gap} = \frac{\mu_r \mu_0 NI}{2\pi r + (\mu_r - 1)L} \approx \frac{\mu_0 NI}{L} \text{ for } \mu L \gg 2\pi r$$

- ↳ the gap makes the biggest contribution to the integral because $H_{\text{gap}} = \mu_r H_{\text{in}} \Rightarrow H_{\text{gap}} \gg H_{\text{in}}$ for a material with very high permeability.
- The magnetic flux across the gap depends on the cross-sectional area of the torus:

$$\phi = \int_S B \cdot d\hat{s} = \frac{A \mu_0 N I}{L}$$

Electromagnetic Induction

- Faraday's law states that a time changing magnetic flux induces an e.m.f proportional to the rate of change of flux.

$$\xi \equiv \oint E \cdot d\hat{l} = - \frac{d}{dt} \int_S B \cdot d\hat{s} \quad (= \frac{d\phi}{dt})$$

- ↳ the e.m.f promotes a current flow whose magnetic field opposes the change that caused it (Lenz's law)
- ↳ using Stokes' theorem, we can write

$$\nabla \times E = - \frac{\partial B}{\partial t}$$

Self-inductance

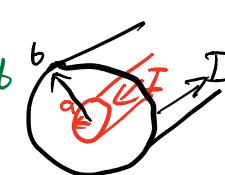
- Self-inductance is the flux linked back to a circuit as a consequence of unit current flowing in the circuit

$$L \equiv \frac{\phi}{I} \quad \leftarrow \text{dependent on geometry}$$

e.g. for a solenoid, $B_{\text{in}} = \mu_0 n I$, $\phi = B_{\text{in}} A \cdot n L$

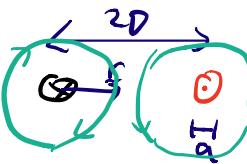
$$\therefore L = \frac{\phi}{I} = \frac{\mu_0 n^2 A I}{I} = \mu_0 n^2 L A$$

e.g. for a coaxial cable, $B(r) = \frac{\mu_0 I}{2\pi r}$ across $b-a$

$$\phi = L \int_a^b B(r) dr \Rightarrow L = \frac{\mu_0 L}{2\pi} \ln(b/a)$$


e.g. for a pair of narrow wires, we first analyse one wire. $B(r) = \frac{\mu_0 I}{2\pi r}$

$$\therefore \Phi/L = \int_a^{2D-a} \frac{\mu_0 I}{2\pi r} dr$$

$$\therefore \frac{L}{I} = \frac{(\Phi_1 + \Phi_2)/L}{I} = \frac{\mu_0}{\pi} \ln\left(\frac{2D}{a}\right)$$


• Self-inductance relates the voltage across a circuit to the rate of change of current. Across some small gap in the circuit $V_{\text{gap}} = \frac{d\Phi}{dt} = L \frac{dI}{dt}$

↳ hence breaking a circuit with high L can create a huge voltage (since $I \rightarrow 0$ very quickly).

• Inductors store energy. In an RL circuit, we have $V = IR + LI$

$$\therefore P = VI = I^2R + \frac{d}{dt}\left(\frac{1}{2}LI^2\right)$$

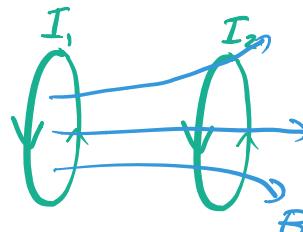
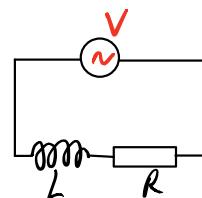
↳ hence the energy stored is

$$U_L = \frac{1}{2}LI^2$$

$$U_C = \frac{1}{2}CV^2$$

↳ similarly for a capacitor:

↳ i.e. inductors store in B -field, capacitors in E -field.



• A circuit can induce an emf in another circuit. The mutual inductance is defined by $M_{21} = \Phi_2/I_1$. In fact, this quantity is symmetric. Proof:

↳ consider $I_1 = I_2 = 0$ initially then gradually increment I_1
 ↳ the energy in the B -field is then $U_1 = \frac{1}{2}L_1 I_1^2$
 ↳ if I_2 is now incremented, it creates $U_2 = \frac{1}{2}L_2 I_2^2$ but also induces an emf in the first coil
 $\therefore U = \frac{1}{2}L_1 I_1^2 + \frac{1}{2}L_2 I_2^2 + M_{12} I_1 I_2$

↳ this must be the same if I_2 was incremented first $\therefore M_{12} = M_{21}$.

• For a simple coupled circuit:

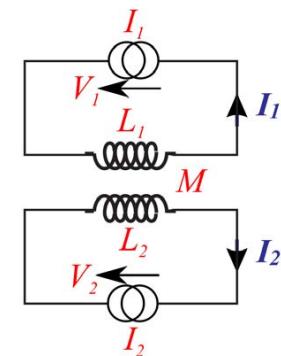
$$V_1 = L_1 \frac{dI_1}{dt} + M \frac{dI_2}{dt}$$

$$V_2 = L_2 \frac{dI_2}{dt} + M \frac{dI_1}{dt}$$

↳ the power of the circuit is

$$P = V_1 I_1 + V_2 I_2$$

$$= \frac{d}{dt} \left[\frac{1}{2} I_1^2 L_1 + \frac{1}{2} I_2^2 L_2 + I_1 I_2 M \right]$$



↳ hence the circuit energy can be derived by circuit analysis.

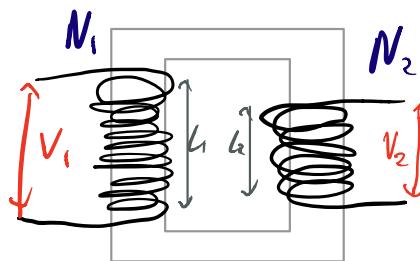
• We can show that $L_1 L_2 \geq M^2$, or equivalently define a coupling coefficient $k = M/\sqrt{L_1 L_2}$, $0 \leq k \leq 1$

↳ $k=1$ means perfect coupling, e.g. a doubly wound solenoid.

↳ essentially a constant times the geometric mean

Transformers

- For an ideal transformer, the same flux passes through both cores, i.e. the coupling constant is unity
 $\Rightarrow \frac{V_2}{V_1} = \frac{N_2}{N_1}$



- Using the expression for the self-inductance of a coil:

$$\frac{L_1}{L_2} = \left(\frac{N_1}{N_2} \right)^2 \frac{L_2}{L_1}$$

- We can analyse how impedance transforms in a transformer circuit, with a sign convention as shown.

$$\phi = LI_1 - MI_2 \quad \text{because } I_2 \text{ in opposite direction}$$

↳ using $V(t) = Ve^{i\omega t}$:

$$V_1 = L_1 \frac{dI_1}{dt} - M \frac{dI_2}{dt} = i\omega L_1 I_1 - i\omega M I_2$$

$$V_2 = -L_2 \frac{dI_2}{dt} + M \frac{dI_1}{dt} = -i\omega L_2 I_2 + i\omega M I_1$$

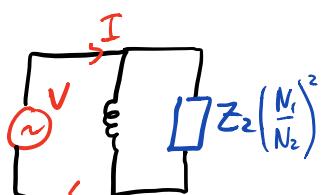
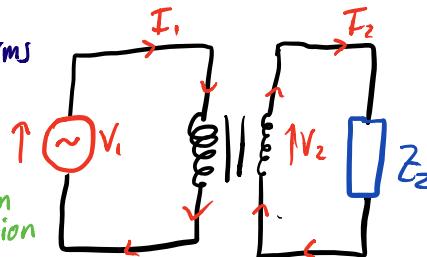
↳ then sub $V_2 = I_2 Z_2$, eliminate I_2 , and rewrite in terms of transformer dimensions.

$$\Rightarrow Z_1 = \frac{i\omega L_1 Z_2 (N_1/N_2)^2}{i\omega L_1 + Z_2 (N_1/N_2)^2}$$

↳ i.e. the input impedance is equivalent to $i\omega L_1$ in parallel with a scaled Z_2

↳ generally, $\omega L_1 \gg Z_2 (N_1/N_2)^2$

$$\Rightarrow Z_1 \approx Z_2 (N_1/N_2)^2$$

Energy flow in resonant circuits

- For an RLC circuit driven with an oscillating current as input:

$$V_R(t) = IR = I_0 R \cos \omega t \Rightarrow P = I_0^2 R \cos^2 \omega t$$

$$V_L(t) = L\dot{I} = -I_0 \omega L \sin \omega t \Rightarrow P = -I_0^2 \omega L \cdot \frac{1}{2} \sin 2\omega t$$

$$V_C(t) = \frac{1}{C} \int I dt = I_0 \frac{1}{\omega C} \sin \omega t \Rightarrow P = I_0^2 \frac{1}{\omega C} \cdot \frac{1}{2} \sin 2\omega t$$

↳ energy is always dissipated by the resistor

↳ energy flow in/out to the magnetic field corresponds to energy flow out/in to the electric field.

- At resonance, the magnetic/electric energy storage perfectly balances, i.e. energy sloshes back and forth between components.

$$\omega L = \frac{1}{\omega C} \Rightarrow \omega_0 = \frac{1}{\sqrt{LC}}$$

Magnetic energy

- for a single circuit,

$$U = \frac{1}{2} L I^2 = \frac{1}{2} \phi I$$

- for two circuits, we can distribute the I_1, I_2, M term equally between circuits and write $U = \frac{1}{2} \phi_1 I_1 + \frac{1}{2} \phi_2 I_2$

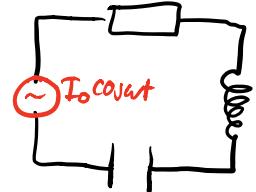
- for a collection of current loops:

ϕ_i is the total flux in loop i

$$U = \frac{1}{2} \sum_{i=1}^N \phi_i I_i$$

* ↳ NB: this includes the self-energies of the loops, i.e. different to electostatics.

↳ it would be the same as the electostatics case iff ϕ_i were defined to be flux due to currents in the other $N-1$ loops.



- For one of these loops:

$$\Phi_i = \int_i \mathbf{B} \cdot d\mathbf{s}_i = \oint_i \mathbf{A} \cdot d\mathbf{l}$$

$$\therefore U = \sum_i \frac{1}{2} (\oint_i \mathbf{A} \cdot d\mathbf{l})$$

↳ this can be generalised to a current in a volume:

$$U = \frac{1}{2} \int_V \mathbf{J} \cdot \mathbf{A} dV \quad \leftarrow \text{analogous to } U = \frac{1}{2} \int_V \rho V dV$$

- Since $\nabla \times \mathbf{H} = \mathbf{J}$, $U = \frac{1}{2} \int_V \mathbf{A} \cdot (\nabla \times \mathbf{H}) dV$

- We can then use a vector identity to expand this and reason about the rate of decay of the quantities as the surface goes to infinity (same as electrostatics)

$$\therefore U_m(r) = \frac{1}{2\mu_0} |\mathbf{B}(r)|^2 = \frac{1}{2} \mathbf{B}(r) \cdot \mathbf{H}(r)$$

energy density



Electromagnetic Waves

- $\nabla \times \mathbf{H} = \mathbf{J}$ is inconsistent with charge cons, which states that $\nabla \cdot \mathbf{J} = -\frac{\partial \rho}{\partial t}$. Hence we must add a displacement current. Maxwell's equations are then:

$$\begin{aligned}\nabla \cdot \mathbf{D} &= \rho \\ \nabla \cdot \mathbf{B} &= 0 \\ \nabla \times \mathbf{E} &= -\dot{\mathbf{B}} \\ \nabla \times \mathbf{H} &= \mathbf{J} + \dot{\mathbf{D}}\end{aligned}$$

- Gauss's theorem charge causes E field
- Gauss's theorem no magnetic monopoles
- Faraday's law E and B are coupled
- Ampere's law current causes B field

- In free space, $\rho=0$ $\mathbf{J}=0$ $\mathbf{D}=\epsilon_0 \mathbf{E}$ $\mathbf{B}=\mu_0 \mathbf{H}$. Thus $\nabla \times \mathbf{E} = -\mu_0 \dot{\mathbf{H}}$. If we take the curl again:

$$\nabla \times (\nabla \times \mathbf{E}) = -\mu_0 \frac{\partial \nabla \times \mathbf{H}}{\partial t} \Rightarrow \nabla^2 \mathbf{E} = \mu_0 \epsilon_0 \frac{\partial^2 \mathbf{E}}{\partial t^2}$$

↳ an identical equation can be derived for $\nabla^2 \mathbf{H}$

↳ this is a wave equation because we can separate $\nabla^2 \mathbf{E} = (\nabla^2 E_x, \nabla^2 E_y, \nabla^2 E_z)$. Thus $c = \sqrt{\mu_0 \epsilon_0}$

- We can look for plane waves propagating in the z direction, where $\frac{\partial \mathbf{E}}{\partial x} = \frac{\partial \mathbf{H}}{\partial y} = 0$.

$$\nabla \times \mathbf{H} = \left(-\frac{\partial H_y}{\partial z}, \frac{\partial H_z}{\partial z}, 0 \right) = \epsilon_0 \frac{\partial \mathbf{E}}{\partial t}$$

↳ $\frac{\partial E_z}{\partial t} = 0$ tells us that EM waves are purely transverse

- ↳ there are two orthogonal polarisations (characterised by the axis of \underline{E}), each with an E - H pair.
 - ↳ both the E_x and H_y are transverse waves with speed c .
 - ↳ For a wave in a dielectric or magnetic material, the refractive index is $n = \sqrt{\epsilon_r \mu_r}$
 - We can use the relationship between the space-derivative of H_y and time-derivative of E_x , along with the form of a plane wave $E_x = R e^{[E_0 \exp(i(cwt - kx))]}$ to show: $\frac{E_x}{H_y} = \frac{k}{\omega \epsilon_0} = \sqrt{\frac{\mu_0}{\epsilon_0}} \approx 377 \Omega$
 - ↳ this quantity is the impedance of free space Z_0
 - ↳ for propagation in some medium, $Z = \sqrt{\mu_r \mu_0 / \epsilon_r \epsilon_0}$
 - ↳ Z can be thought of as quantifying the 'response' (H) as a result of a 'disturbance' (E).
 - For a general plane wave:

$$\hat{E}(x, t) = E_0 \exp[i(\underline{k} \cdot \underline{x} - cwt)]$$

$$\hat{H}(x, t) = H_0 \exp[i(\underline{k} \cdot \underline{x} - cwt)]$$

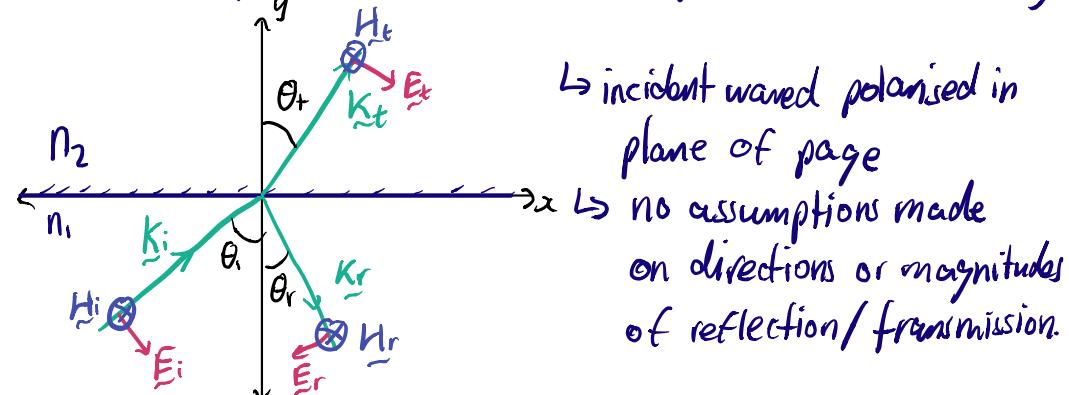
remember to take real parts
 - ↳ it is easy to show $\nabla \cdot \underline{E} = i \underline{k} \cdot \underline{E}$ (likewise for \underline{H})
 - $$\nabla \times \underline{E} = i \underline{k} \times \underline{E}$$
 - ↳ thus: $\underline{k} \times \underline{E}_0 = c \omega \mu_0 \underline{H}_0$ } $\underline{E}, \underline{H}, \underline{k}$ form a right-handed system
 $\underline{k} \times \underline{H}_0 = -\omega \epsilon_0 \underline{E}_0$ }
 - ↳ also, $\underline{H}_0 = \frac{1}{Z_0} \underline{k} \times \underline{E}_0$ → more general than $|E| = Z|H|$
 - Because of Fourier theory, any field can be described as some (possibly infinite) series of plane waves
 - $$\underline{E}(x, t) = \iiint A_s(\underline{k}, \omega) e^{i \underline{k} \cdot \underline{x}} e^{i \omega t} d^3k d\omega$$
 - ↳ A_s is the spectral function
 - ↳ note that the K 's are not independent
- ### Energy flow
- The rate at which work is done by a field on a charge is: $P = \frac{d}{dt} (q \underline{E} \cdot d\underline{l}) = q \underline{E} \cdot \underline{v}$
 - ↳ for a charge distribution: $P = \int_V \underline{E} \cdot \underline{J} dV$
 - * ↳ hence the power dissipated by a current per unit volume is: $P/V = \underline{E} \cdot \underline{J}$
 - To calculate the power flux, we analyse the quantity: $\nabla \cdot (\underline{E} \times \underline{H}) = \underline{H} \cdot (\nabla \times \underline{E}) - \underline{E} \cdot (\nabla \times \underline{H})$
 - ↳ by substituting from Maxwell and taking the volume integral (using div. theorem on LHS):
 - $$-\oint_S (\underline{E} \times \underline{H}) \cdot d\underline{s} = \int_V \left(\frac{\partial}{\partial t} \left[\frac{1}{2} \mu_0 \underline{H} \cdot \underline{H} \right] + \frac{\partial}{\partial t} \left[\frac{1}{2} \epsilon_0 \underline{E} \cdot \underline{E} \right] + \underline{E} \cdot \underline{J} \right) dV$$

defines propagation rate of increase in stored energy energy dissipated
 - Thus since the RHS is the change in power, $\underline{E} \times \underline{H}$ must be the power flux into the volume.

- This defines the Poynting vector: $\underline{N} = \underline{E} \times \underline{H}$
 - ↳ quantifies the direction and magnitude of the power flux
 - ↳ nonlinear in field so cannot be superposed.
 - ↳ e.g. for a plane wave travelling in $+z$, $\underline{E} = (E_x, 0, 0)$, $\underline{H} = (0, H_y, 0) \Rightarrow \underline{N} = (0, 0, E_x^2/z)$
- If we are instead using complex vector fields $\hat{\underline{E}}$ and $\hat{\underline{H}}$, the average power flux is: $\frac{1}{2} \operatorname{Re} [\hat{\underline{E}} \times \hat{\underline{H}}^*]$
 - ↳ the max rate at which energy sloshes back and forth is given by: $\frac{1}{2} \operatorname{Im} [\hat{\underline{E}} \times \hat{\underline{H}}^*]$
 - ↳ when \underline{E} and \underline{H} are in phase, the complex power is a real quantity
- For a wave normally incident on an absorbing surface, the energy density is given by $\frac{\text{power}}{\text{volume}} \times 1 \text{ second}$
 $\therefore U = \frac{|\underline{N}| \cdot A}{c} = |\underline{N}| \cdot A / A c dt = |\underline{N}| / c$
 - ↳ for a photon, $E = pc \Rightarrow U = g/c$ where g is the radiation momentum density
 - ↳ hence $g = \underline{N}/c^2$, and $d\underline{p} = g A c dt$
- The radiation pressure is the rate of change of momentum per unit area. $R = g c \Rightarrow \underline{R} = \underline{N}/c$
 - ↳ $|R|$ doubles if the surface reflects radiation.

Reflection and transmission

- Consider a plane wave incident on a plane dielectric boundary



- ↳ incident wave polarised in plane of page
- ↳ no assumptions made on directions or magnitudes of reflection/transmission.
- On the x -axis, the parallel components of the fields must be continuous:

$$\begin{aligned} E_{i0} \exp[i(k_i x \sin \theta_i - \omega_i t)] \cos \theta_i \\ = E_{r0} \exp[i(k_r x \sin \theta_r - \omega_r t)] \cos \theta_r \\ = E_{t0} \exp[i(k_t x \sin \theta_t - \omega_t t)] \cos \theta_t \end{aligned}$$

↳ this can only be true in general if their phases match. Thus:

$$\begin{aligned} \omega_i &= \omega_r = \omega_t \\ k_i \sin \theta_i &= k_r \sin \theta_r = k_t \sin \theta_t \end{aligned}$$

↳ but k depends on n via $k = n \omega/c$

↳ hence: $\theta_i = \theta_r \leftarrow \text{law of reflection}$
 $n_i \sin \theta_i = n_r \sin \theta_r \leftarrow \text{Snell's law.}$

- We can then analyse the power transmitted and reflected
- $$(E_{i0} - E_{r0}) \cos \theta_i = E_{t0} \cos \theta_t$$

↳ then match H_{\parallel} : $H_{i0} + H_{r0} = H_{t0}$
 $\Rightarrow n_i (E_{i0} + E_{r0}) = n_r E_{t0} \quad \boxed{\frac{E}{H} = \frac{n_0}{n}}$

↳ these 2 eqs can be solved for 2 unknowns:

$$r_{||} = \frac{E_{r0}}{E_0} = \frac{\tan(\theta_i - \theta_t)}{\tan(\theta_i + \theta_t)}$$

$$t_{||} = \frac{E_{t0}}{E_0} = \frac{2\cos\theta_i}{(n_2/n_1)\cos\theta_i + \theta_t}$$

- This assumed that the E field was polarised along the plane of incidence. We can instead derive it for the case that E is polarised perpendicular to the page:

$$r_{\perp} = \frac{E_{r0}}{E_0} = -\frac{\sin(\theta_i - \theta_t)}{\sin(\theta_i + \theta_t)}$$

$$t_{\perp} = \frac{E_{t0}}{E_0} = \frac{2\cos\theta_i}{\cos\theta_i + (n_2/n_1)\cos\theta_t}$$

- These equations are **Fresnel's relations**, and explain a number of optical phenomena.
- For normally incident light, we can use a small-angle approximation to find the power reflection coefficient:

$$R_{||} = |r_{||}|^2 = \left(\frac{n-1}{n+1}\right)^2 \quad \text{← same for } R_{\perp}, r_{\perp}$$

- There is a particular angle for which $r_{||}=0$. This is the **Brewster angle**: $\tan\theta_B = n_2/n_1$.
- If $n_1 > n_2$ (e.g. glass-air), there is a **critical angle** beyond which total internal reflection occurs. $\sin\theta_c = n_1/n_2$
- ↳ an evanescent wave is produced, travelling along the surface.

Waves in plasmas

- A plasma is a region of space where free electrons and their parent ions are present. We assume that ions are stationary, thus the electrons obey:

$$me \frac{d^2 E}{dt^2} = -e(E + v \times B)$$

- ↳ electrons in plasmas are not fast, and we know that for a plane wave $E_x = cB_y$. Hence $v \times B$ can be ignored. Hence $E = \frac{e}{me\omega} E_0 \exp[i(kz - \omega t)]$

- ↳ i.e. electrons oscillate around their ions with amplitude inversely proportional to the radiation freq.

- The separation of electron from ion creates a dipole:

$$P = -eE = -\frac{e^2}{me\omega^2} E$$

- ↳ we can then analyse the relationship between the electric field and the polarisation to derive the plasma's permittivity:

number density $P = n_e P = -\frac{n_e e^2}{me\omega^2} E$ and $P = \epsilon_0 (\epsilon_r - 1) E$

$$\epsilon_r = 1 - \frac{\omega_p^2}{\omega^2}, \quad \omega_p^2 = \frac{n_e e^2}{\epsilon_0 m_e}$$

- ω_p is the plasma frequency, and is a materials property.
- ↳ using the dielectric formalism allows us to analyse behaviour in the same way as we would an insulator.

- The refractive index of a dielectric is $n = \sqrt{\epsilon_r \mu_r}$ hence for a plasma: $n = \sqrt{\epsilon_r} = \sqrt{1 - \frac{\omega_p^2}{\omega^2}}$

- The refractive index is imaginary when the radiation freq is below the plasma frequency.

$$n = i\beta \Rightarrow k = \frac{n\omega}{c} = \frac{i\beta}{c}$$

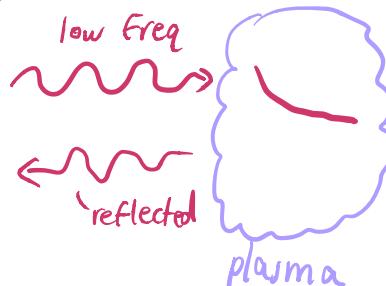
$$\therefore \tilde{E} = E_0 \exp\left[-\frac{\omega\beta z}{c}\right] \exp[-i\omega t]$$

↳ i.e there is a non-propagating evanescent wave

↳ the magnetic field is:

$$H_y = \sqrt{\epsilon_r \mu_0} = \frac{i\beta}{z_0} E_x$$

↳ because E_x and H_y are out of phase, the average power transmitted is zero.



↳ hence all energy must be reflected.

- Above the plasma frequency, the travelling waves are dispersive: $V_p = \frac{\omega}{k} = \frac{c}{n} = c \left(1 - \frac{\omega_p^2}{\omega^2}\right)^{-1/2}$

$$V_g = \frac{dk}{d\omega} = c \sqrt{1 - \frac{\omega_p^2}{\omega^2}}$$

↳ while $V_p > c$, it is the group velocity that carries information and $V_g < c$.

↳ $V_g V_p = c^2$, which applies to waveguides also.

Waves in conducting media

- From Maxwell's equations: $\nabla \times H = I + \frac{\partial D}{\partial t} = \sigma E + \epsilon_0 \frac{\partial E}{\partial t}$

↳ assuming plane waves for \tilde{E} and \tilde{H} :

$$\nabla \times \tilde{H} = -i\omega \epsilon_0 \left(\epsilon_r + \frac{i\sigma}{\omega \epsilon_0}\right) \tilde{E}$$

↳ we can thus model a real conductor as a dielectric with constant: $\epsilon_r' = \left(\epsilon_r + \frac{i\sigma}{\omega \epsilon_0}\right)$

- In a good conductor, the imaginary part is much greater so $\epsilon_r' \approx \frac{i\sigma}{\omega \epsilon_0}$. The refractive index is thus complex: $n = \sqrt{\epsilon_r \mu_r} = \pm (1+i) \sqrt{\frac{\sigma \mu_r}{2 \omega \epsilon_0}}$

↳ with $k = \frac{\omega}{c/n} = \frac{\omega}{n} \sqrt{\mu_0 \epsilon_0}$, the solution for \tilde{E} is:

$$\tilde{E} = E_0 \exp\left[-\frac{z}{\delta}\right] \exp\left[i\left(\frac{z}{\delta} - \omega t\right)\right]$$

where $\delta = \sqrt{\frac{2}{\sigma \omega \mu_0 \epsilon_0}}$ is the skin depth

↳ the skin depth thus characterises the amplitude decay of the travelling wave in a conductor.

- A conductor introduces a $\pi/4$ phase difference between E, H

↳ impedance is now complex

↳ power is dissipated in the conductor.

- Consider a wire carrying a current with freq ω
 - because of the finite conductivity of the material, there is an E field on the surface. Combined with the B field from the wire, there is N pointing radially inwards
 - this energy flow must decay based on the skin depth
 - we define a new coordinate $x = a - r$:
$$J_z = J_0 \exp\left[-\frac{x}{\delta}\right] \exp[i(\frac{x}{\delta} - \omega t)]$$
- Hence alternating currents tend to flow on the surface of the wire – this is the **skin effect**
 - because the current is confined in a smaller region, the resistance of the wire increases as freq \uparrow .
$$\hat{I} = \int J_z ds \approx 2\pi a \int J_z(x) dx$$

integrate to ∞ because of exponential decay

$$\therefore \hat{I} \approx 2\pi a J_0 \exp[-i\omega t] \int_0^\infty \exp\left[\frac{x}{\delta}(i-1)\right] dx$$

$$\Rightarrow \hat{I} = \pi a J_0 \delta (1+i) e^{-i\omega t}$$

$$\Rightarrow \langle I(t) \rangle^2 = (\pi a J_0 \delta)^2$$
 - similarly, $\langle J_z(t) \rangle^2 = \frac{1}{2} J_0^2 \exp\left[-\frac{2x}{\delta}\right]$
 - $dP = I^2 R = \frac{J^2 dA}{\sigma} L$ and P is found by integrating
 - $R = \rho / \langle I(t) \rangle^2 = \frac{1}{2\pi a \delta}$
 - The resistance per unit length is as if all current flowed uniformly in a shell of thickness δ



Guided waves

- For long wires ($d > \lambda$), we must take into account the fact that V and I have position-dependence (since they are the result of EM waves).
 - d is the dimension of the circuit
- Transmission lines can be used for $d \approx \lambda$, while for $\lambda \ll d$ we need waveguides.

Transmission lines

- Wires not only conduct current, they guide EM energy.
- The simplest transmission line setup is a pair of wires
 - using L and C per unit length:

$$dV = V_2 - V_1 = -(L dz) \frac{\partial I}{\partial t}$$

$$dI = I_2 - I_1 = -(C dz) \frac{\partial V}{\partial t}$$

in the limit $dz \rightarrow 0$:

$$\frac{\partial V}{\partial z} = -L \frac{\partial I}{\partial t} \quad \frac{\partial I}{\partial z} = -C \frac{\partial V}{\partial t}$$

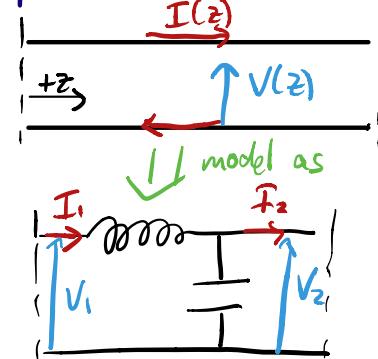
$$\Rightarrow \frac{\partial^2 V}{\partial t^2} = \frac{1}{LC} \frac{\partial^2 V}{\partial z^2} \quad \frac{\partial^2 I}{\partial t^2} = \frac{1}{LC} \frac{\partial^2 I}{\partial z^2}$$

hence there are voltage and current waves with $V = t \frac{1}{\sqrt{LC}}$

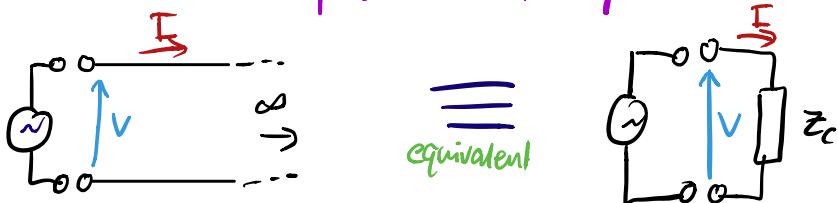
with the engineering convention $V = V_0 \exp[i(\omega t - kz)]$,

$$kV = \omega L I \Rightarrow Z = \frac{V}{I} = \sqrt{\frac{L}{C}}$$

this is the **characteristic impedance** of the line, Z_c

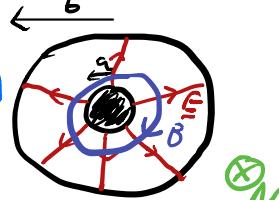


- We could replace the transmission line with a load of impedance $Z = Z_c$ without changing the behaviour at the terminals \Rightarrow impedance matching.



- For the pair of wires, $C = \frac{\pi \epsilon_0}{\ln(2D/a)}$ $L = \frac{\mu_0}{\pi} \ln(2D/a)$
 $\Rightarrow Z = Z_0 \frac{\ln(2D/a)}{\pi}$

\hookrightarrow if we fill the space between them with a dielectric, $Z' = \frac{Z}{n}$



- For a coaxial cable, $C = \frac{2\pi \epsilon_0}{\ln(b/a)}$ $L = \frac{\mu_0}{2\pi} \ln(b/a)$
 $\Rightarrow Z = Z_0 \frac{\ln(b/a)}{2\pi}$

\hookrightarrow most cables are manufactured with $Z=50\Omega$ or $Z=75\Omega$
 \hookrightarrow the cable may be partially filled with dielectrics, but will only support a transverse EM wave if there is radial symmetry (i.e. cylinders).

- On PCBs, a useful setup is the strip transmission line. For $d \ll a$:
 ignore edge effects

$$C = \frac{\epsilon_r \epsilon_0 a}{d}, \quad L = \frac{\mu_0 d}{a} \Rightarrow Z = Z_0 \frac{d}{a}$$

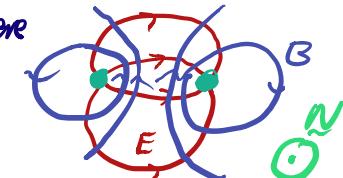
\hookrightarrow hence Z can be controlled by changing the width of the conductor.

\hookrightarrow in reality we would use more complicated equations that describe edge effects.

\hookrightarrow technically a TEM wave is not supported since the dielectric only fills half of space, but it is a good approx if λ much bigger than the dimensions of the circuit a and d (i.e. low freqs).

Power flow on transmission lines

- For most setups, B and E are everywhere perpendicular, so the Poynting vector always points along the wire.



- We can quantify the power as the negative of the rate of change of stored energy:

$$-\dot{U} = - \int_a^b \frac{1}{2} LI^2 + \frac{1}{2} CV^2 dz$$

$$\Rightarrow -\frac{dU}{dt} = - \int_a^b LI \frac{\partial I}{\partial t} + CV \frac{\partial V}{\partial t} dz$$

using transmission-line equations

$$= \int_a^b I \frac{\partial V}{\partial z} + V \frac{\partial I}{\partial z} dz$$

$$= [IV]_b - [IV]_a$$

\hookrightarrow hence $P=VI$ as expected.

- If we terminate a transmission line with a load that matches Z_c , the load absorbs all the power.

- If the line is terminated with an impedance that doesn't match Z_c , some power will be reflected.

$$V_i = V_1 \exp[j(\omega t - kz)]$$

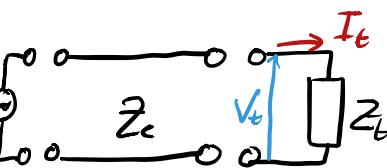
$$I_i = I_1 \exp[j(\omega t + kz)]$$

incident

$$\hookrightarrow \text{matching B.Cs, } V_t = V_i + V_r$$

$$I_t = I_i + I_r$$

$$Z_t = \frac{V_t}{I_t}$$



$$V_r = V_2 \exp[j(\omega t + kz)]$$

$$I_r = I_2 \exp[j(\omega t + kz)]$$

reflected

place origin ($z=0$)

whichever easiest.
In this case, at load

\hookrightarrow this gives us the voltage reflection coefficient

$$r_v = \frac{V_1}{V_2} = \frac{Z_t - Z}{Z_t + Z}$$

\hookrightarrow we can find the current reflection coefficient to get the total power.

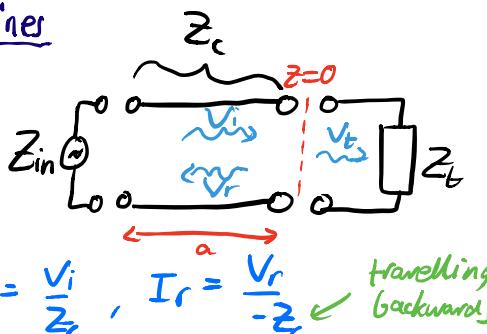
Input Impedances of transmission lines

- Consider a mismatched line with

$Z_{in} = Z_c$ such that the source absorbs all reflections

$$Z_{in} = \left. \frac{V_i + V_r}{I_i + I_r} \right|_{z=-a}, \quad I_i = \frac{V_i}{Z_c}, \quad I_r = \frac{V_r}{-Z_c}$$

$$\therefore \frac{Z_{in}}{Z_c} = \frac{Z_c \cos ka + i Z_c \sin ka}{Z_c \cos ka + i Z_t \sin ka}$$



travelling
backwards

\hookrightarrow hence the dimension of the circuit defines the response

- For a shorted line, $Z_t = 0 \Rightarrow \frac{Z_{in}}{Z_c} = i \tan ka$

\hookrightarrow purely imaginary since the load cannot absorb power

\hookrightarrow thus a shorted wire can be used to synthesise an impedance.

\hookrightarrow similarly, for an open-circuited line $Z_t \rightarrow \infty \Rightarrow \frac{Z_{in}}{Z_c} = -i \cot ka$

- For the special case of a quarter-wavelength line, $\cos ka = 0$

$$\therefore \frac{Z_{in}}{Z_c} = \frac{Z_c}{Z_t} \Rightarrow Z_{in} = \frac{Z_c^2}{Z_t}$$

\hookrightarrow hence the $\lambda/4$ line ensures there is no reflection

\hookrightarrow this only works for a single frequency

Waveguides

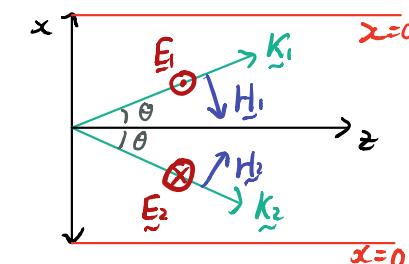
- Losses in transmission lines increase significantly at very high freqs due to the skin effect.

- Waveguides allow EM waves to be propagated through hollow tubes, without the need for a second conductor.

\hookrightarrow transmission lines are simple special cases of waveguides that can be analysed in terms of V and I

rather than E and H .

\hookrightarrow we consider two plane waves with wavevectors K_1, K_2 travelling at angles $\pm\theta$ to the z -axis.



- By considering the resultant E field:

$$\begin{aligned} E_y &= E_0 (\exp[i(k_x \cdot r)] - \exp[i(k_z \cdot r)]) e^{-i\omega t} \\ &= E_0 (\exp[i(k_x \sin \theta + k_z \cos \theta)] - \exp[i(-k_x \sin \theta + k_z \cos \theta)]) e^{-i\omega t} \\ \therefore E_y &= E_0 \exp[i(k_z \cos \theta) \omega t] \cdot 2i \sin(k_x \sin \theta). \end{aligned}$$

↳ we can then fit the B.Cs of conducting plates at $x=0, z=a$, hence $k_x \sin \theta = m\pi \Rightarrow k_x = \frac{m\pi}{a}, m \in \mathbb{Z}$

↳ hence there is a standing wave between the plates and a propagating wave in the $+z$ direction.

↳ this solution also fits the B.Cs for the H field: $H_z = 0$ inside and just outside the conductor.

↳ there may be a nonzero H_{yy} , but if there is no field inside the conductor, this B.C can only be satisfied by a sheet of current (by Ampere's law)

↳ hence current will flow in a waveguide, which decay into the conductor via the skin effect.

The effective wavevector for propagation is $k_g = k \cos \theta$, so the phase velocity is: $v_p = \frac{\omega}{k_g} = \frac{\omega}{k \cos \theta} = \frac{c}{\cos \theta}$

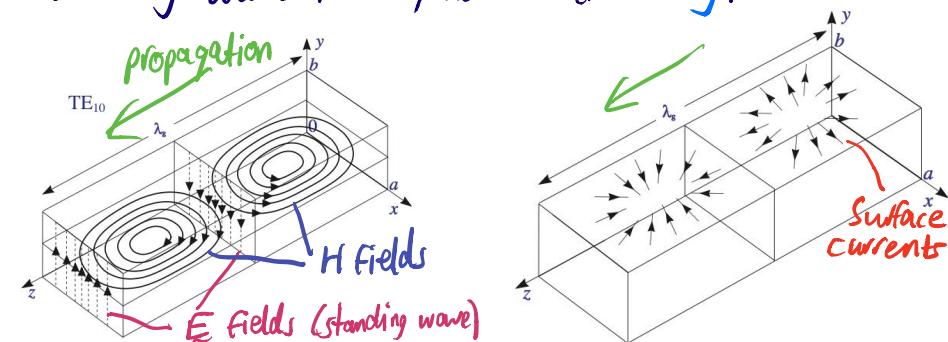
↳ $v_p \geq c$, but this is fine since only the group velocity propagates information

Because of the vertical standing wave, only certain frequencies of the propagating wave are possible.

$$k^2 = k_x^2 + k_g^2 \Rightarrow k_g^2 = k^2 - \frac{m^2 \pi^2}{a^2}$$

- For $\alpha L \gtrsim \frac{\lambda}{2}$, the standing wave cannot be satisfied
 - ↳ this could be a good thing, e.g. for a two-strip transmission line, waveguide behaviour is not desired.
 - ↳ for high freqs, the only solution is to make the liner very small.

- We can now introduce conducting plates in the y direction
 - ↳ since E is in the y direction, $E_{yy} = 0$ as required
 - ↳ $H_y = 0$ so the B.C for H is automatically satisfied.
- We then have a rectangular waveguide, which supports a transverse electric (TE) wave.
 - ↳ the H field is not transverse, so this is not a TEM wave (unlike for transmission lines).
 - ↳ the lowest TE mode is TE_{10} , i.e. lowest order standing wave in x , no variation in y .



↳ we can make cuts in the waveguide walls to introduce components, but they must not prevent current flow.

- The solution for a general TE_{mn} mode is:

$$\underline{E}_x = A_0 k_y \cos(k_x x) \sin(k_y y) \cos(k_z z - \omega t)$$

$$\underline{E}_y = -A_0 k_x \sin(k_x x) \cos(k_y y) \cos(k_z z - \omega t)$$

$$\underline{E}_z = 0$$

with $(k_x, k_y, k_z) = \left(\frac{m\pi}{a}, \frac{n\pi}{b}, k_g \right)$, $m, n \in \mathbb{Z}$

Since $|k_s|^2 = \frac{\omega^2}{c^2}$ by definition:

$$k_g^2 = \frac{\omega^2}{c^2} - \frac{m^2\pi^2}{a^2} - \frac{n^2\pi^2}{b^2}$$

↳ for a propagating wave, $k_g^2 > 0$, hence the cutoff frequency is $f_c = \sqrt{\frac{m^2}{4a^2} + \frac{n^2}{4b^2}}$

↳ below this there can only be evanescent waves.

Summary of Important Formulae

Maxwell's Equations

Free space:

$$\nabla \cdot \underline{E} = \frac{\rho}{\epsilon_0}$$

$$\nabla \times \underline{E} = -\frac{\partial \underline{B}}{\partial t}$$

$$\nabla \cdot \underline{B} = 0$$

$$\nabla \times \underline{B} = \mu_0 \underline{J} + \frac{\mu_0 \epsilon_0}{\epsilon_0} \frac{\partial \underline{E}}{\partial t}$$

$$\underline{D} = \epsilon_0 \underline{E} + \underline{\rho}$$

SAME

Matter:

$$\nabla \cdot \underline{D} = \rho_{free}$$

$$\nabla \times \underline{E} = -\frac{\partial \underline{B}}{\partial t}$$

$$\nabla \cdot \underline{B} = 0$$

$$\nabla \times \underline{H} = \underline{J}_{free} + \frac{\partial \underline{D}}{\partial t}$$

D and H

$$\underline{D} = \epsilon_0 \underline{E} + \underline{\rho}$$

$$\underline{H} = \frac{1}{\mu_0} \underline{B} + \underline{M}$$

$$\underline{P} = \epsilon_0 \chi \underline{E}$$

$$\underline{M} = \chi_m \underline{H}$$

$$\underline{D} = \epsilon_r \epsilon_0 \underline{E}$$

$$\underline{B} = \mu_r \mu_0 \underline{H}$$

Lorentz force law: $\underline{F} = q(\underline{E} + \underline{v} \times \underline{B})$

Power: $U = \frac{1}{2} \int_V \epsilon_0 E^2 + \frac{1}{\mu_0} B^2 dV$

$$\underline{N} = \underline{E} \times \underline{H}$$